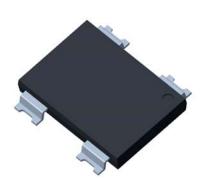
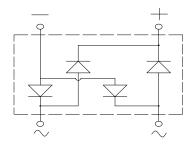






# **Fast Recovery Bridge Rectifiers**





#### **Features**

- UL recognition, file #E313149
- Glass passivated chip junction
- Ideal for automated placement
- High surge current capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

#### Typical Applications

General purpose use in AC/DC bridge full wave rectification for SMPS, lighting ballaster, adapter, battery charger, home appliances, office equipment, and telecommunication applications.

#### **Mechanical Data**

• Package: YBS2G

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, Halogen-free

• Terminals: Tin plated leads, solderable per

J-STD-002 and JESD22-B102

• Polarity: As marked on body

### ■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	RYBSA4010
Device marking code			RYBSA4010
Maximum Repetitive Peak Reverse Voltage	VRRM	V	1000
Maximum RMS Voltage	VRMS	V	700
Maximum DC blocking Voltage	VDC	V	1000
Average rectified output current @60Hz sine wave, R-load, Tc=85°C	lo	Α	4.0
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave,1 cycle, Tj=25°C	Ison	А	120
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25°C	IFSM		240
Current squared time @1ms≤t≤8.3ms Tj=25°C, Rating of per diode	I²t	A <sup>2</sup> s	59.8
Storage temperature	T <sub>stg</sub>	°C	-55 ~ +150
Junction temperature	Tj	°C	-55 ~ +150

## RYBSA4010

**■Electrical Characteristics** (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	RYBSA4010
Maximum reverse recovery time	<b>t</b> <sub>rr</sub>	ns	I <sub>F</sub> =0.5A,I <sub>R</sub> =1.0A, I <sub>n</sub> =0.25A	500
Maximum instantaneous forward voltage drop per diode	VF	V	IFM=2.0A	1.3
Maximum DC reverse current at rated DC blocking voltage	IR		T <sub>j</sub> =25℃	5
per diode		μA	T <sub>j</sub> =125°C	100
Typical junction capacitance	Cj	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	40

## **■Thermal Characteristics** $(T_a=25$ $^{\circ}$ C Unless otherwise specified)

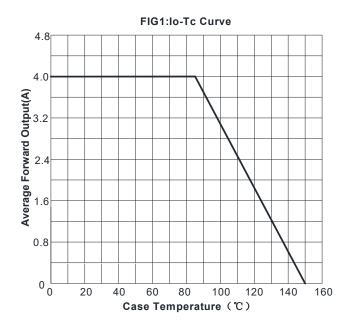
PARAMETER		SYMBOL	UNIT	RYBSA4010
	Between Junction and Ambient	$R_{\theta J-A}$		55
Typical Thermal Resistance	Between Junction and Lead	$R_{ heta J ext{-}L}$	°C/W	10
	Between Junction and Case	$R_{ heta J-C}$		7

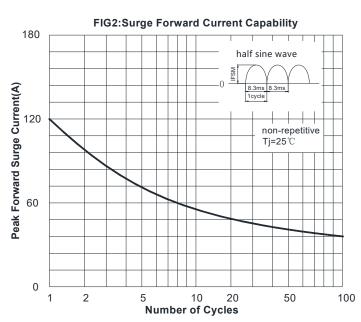
Note: Device mounted on P.C.B with 35mm\*25mm\*1.7mm.

**■**Ordering Information (Example)

PREFERED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
RYBSA4010	F1	Approximate 0.274	2500	1	35000	13" reel

### **■ Characteristics** (Typical)







## **RYBSA4010**

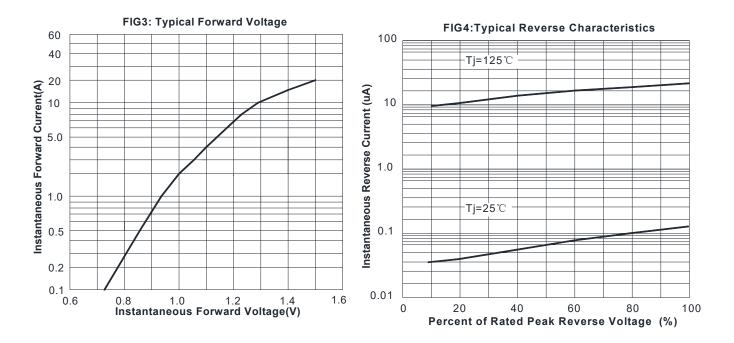
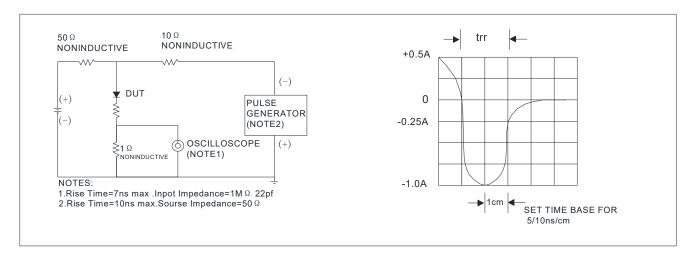


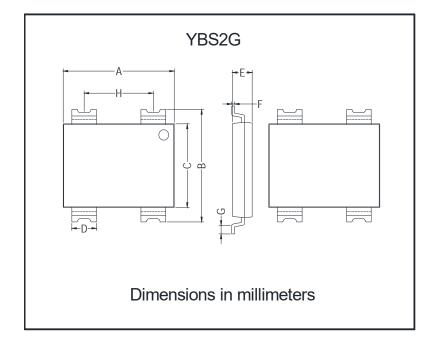
FIG.5: Diagram of circuit and Testing wave form of reverse recovery time





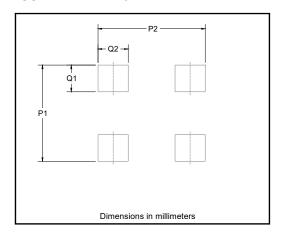


### **■ Outline Dimensions**



YBS2G				
Dim	Min	Max		
Α	8.6	9.2		
В	8.3	8.9		
С	6.2	6.6		
D	1.85	2.15		
E	1.35	1.75		
F	0.1	0.3		
G	0.4	0.8		
Н	5.4	5.8		

## ■ Suggested pad layout



YBS2G		
Dim	Min	
P1	11	
P2	7.8	
Q1	2.4	
02	2.2	



## RYBSA4010

#### **Disclaimer**

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